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## H11L1M, H11L2M, H11L3M 6-Pin DIP Schmitt Trigger Output Optocoupler

## Features

- High Data Rate, 1 MHz Typical (NRZ)

■ Free from Latch-up and Oscilliation Throughout Voltage and Temperature Ranges
$\square$ Microprocessor Compatible Drive
■ Logic Compatible Output Sinks 16 mA at 0.4 V Maximum
■ Guaranteed On/Off Threshold Hysteresis

- Wide Supply Voltage Capability, Compatible with All

Popular Logic Systems
■ Safety and Regulatory Approvals:

- UL1577, 4,170 VAC RMs for 1 Minute
- DIN-EN/IEC60747-5-5, 850 V Peak Working Insulation Voltage


## Applications

■ Logic-to-Logic Isolator

- Programmable Current Level Sensor
- Line Receiver-Eliminate Noise and Transient Problems
- AC to TTL Conversion-Square Wave Shaping

Digital Programming of Power Supplies

- Interfaces Computers with Peripherals


## Description

The H11LXM series has a high-speed integrated circuit detector optically coupled to a gallium-arsenide infrared emitting diode. The output incorporates a Schmitt trigger, which provides hysteresis for noise immunity and pulse shaping. The detector circuit is optimized for simplicity of operation and utilizes an open-collector output for maximum application flexibility.

Schematic


Figure 1. Schematic

## Package Outlines



Figure 2. Package Outlines

## Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Parameter |  | Characteristics |
| :--- | :--- | :---: |
| Installation Classifications per DIN VDE | $<150 \mathrm{~V}_{\text {RMS }}$ | I-IV |
| $0110 / 1.89$ Table 1, For Rated Mains Voltage | $<300 \mathrm{~V}_{\text {RMS }}$ | I-IV |
| Climatic Classification | $55 / 100 / 21$ |  |
| Pollution Degree (DIN VDE 0110/1.89) | 2 |  |
| Comparative Tracking Index | 175 |  |


| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{PR}}$ | Input-to-Output Test Voltage, Method $\mathrm{A}, \mathrm{V}_{\text {IORM }} \times 1.6=\mathrm{V}_{\mathrm{PR}}$, <br> Type and Sample Test with $\mathrm{t}_{\mathrm{m}}=10 \mathrm{~s}$, Partial Discharge $<5 \mathrm{pC}$ | 1360 | $\mathrm{~V}_{\text {peak }}$ |
|  | Input-to-Output Test Voltage, Method B, $\mathrm{V}_{\text {IORM }} \times 1.875=\mathrm{V}_{\mathrm{PR}}$, <br> $100 \%$ Production Test with $\mathrm{t}_{\mathrm{m}}=1 \mathrm{~s}$, Partial Discharge $<5 \mathrm{pC}$ | 1594 | $\mathrm{~V}_{\text {peak }}$ |
|  | Maximum Working Insulation Voltage | 850 | $\mathrm{~V}_{\text {peak }}$ |
| $\mathrm{V}_{\text {IOTM }}$ | Highest Allowable Over-Voltage | 6000 | $\mathrm{~V}_{\text {peak }}$ |
|  | External Creepage | $\geq 7$ | mm |
|  | External Clearance | $\geq 7$ | mm |
|  | External Clearance (for Option TV, 0.4" Lead Spacing) | $\geq 10$ | mm |
| DTI | Distance Through Insulation (Insulation Thickness) | $\geq 0.5$ | mm |
| $\mathrm{~T}_{\mathrm{S}}$ | Case Temperature ${ }^{(1)}$ | 175 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{S}, \text { INPUT }}$ | Input Current ${ }^{(1)}$ | 350 | mA |
| $\mathrm{P}_{\mathrm{S}, \mathrm{OUTPUT}}$ | Output Power ${ }^{(1)}$ | 800 | mW |
| $\mathrm{R}_{\text {IO }}$ | Insulation Resistance at $\mathrm{T}_{\mathrm{S}}, \mathrm{V}_{\text {IO }}=500 \mathrm{~V}^{(1)}$ | $>10^{9}$ | $\Omega$ |

## Note:

1. Safety limit values - maximum values allowed in the event of a failure.

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified.

| Symbol | Parameters | Value | Units |
| :---: | :---: | :---: | :---: |
| Total Device |  |  |  |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |
| T OPR | Operating Temperature | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction Temperature | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {SOL }}$ | Lead Solder Temperature | 260 for 10 seconds | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Total Device Power Dissipation at $25^{\circ} \mathrm{C}$ Derate Above $25^{\circ} \mathrm{C}$ | 250 | mW |
|  |  | 2.94 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| Emitter |  |  |  |
| $\mathrm{I}_{\mathrm{F}}$ | Continuous Forward Current | 30 | mA |
| $\mathrm{V}_{\mathrm{R}}$ | Reverse Voltage | 6 | V |
| $\mathrm{I}_{\mathrm{F}}(\mathrm{pk})$ | Forward Current - Peak ( $1 \mu \mathrm{~s}$ pulse, 300 pps ) | 100 | mA |
| $\mathrm{P}_{\mathrm{D}}$ | LED Power Dissipation | 60 | mW |
| Detector |  |  |  |
| $\mathrm{P}_{\mathrm{D}}$ | Detector Power Dissipation | 150 | mW |
| $\mathrm{V}_{\mathrm{O}}$ | $\mathrm{V}_{45}$ Allowed Range | 0 to 16 | V |
| $\mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{65}$ Allowed Range | 3 to 16 | V |
| $\mathrm{I}_{0}$ | $\mathrm{I}_{4}$ Output Current | 50 | mA |

## Electrical Characteristics

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified.
Individual Component Characteristics

| Symbol | Parameters | Test Conditions | Device | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Emitter |  |  |  |  |  |  |  |
| $V_{F}$ | Input Forward Voltage | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ | All |  | 1.2 | 1.5 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=0.3 \mathrm{~mA}$ |  | 0.75 | 1.0 |  |  |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | $\mathrm{V}_{\mathrm{R}}=3 \mathrm{~V}$ | All |  |  | 10 | $\mu \mathrm{A}$ |
| $\mathrm{C}_{J}$ | Capacitance | $\mathrm{V}=0, \mathrm{f}=1.0 \mathrm{MHz}$ | All |  |  | 100 | pF |
| Detector |  |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{CC}}$ | Operating Voltage Range |  | All | 3 |  | 15 | V |
| $\mathrm{I}_{\mathrm{CC} \text { (off) }}$ | Supply Current | $\mathrm{I}_{\mathrm{F}}=0, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$ | All |  | 1.6 | 5.0 | mA |
| $\mathrm{IOH}^{\text {I }}$ | Output Current, High | $\mathrm{I}_{\mathrm{F}}=0, \mathrm{~V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{O}}=15 \mathrm{~V}$ | All |  |  | 100 | $\mu \mathrm{A}$ |

## Transfer Characteristics

| Symbol | Parameter | Test Conditions | Device | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DC Characteristics |  |  |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{CC} \text { (on) }}$ | Supply Current | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$ | All |  | 1.6 | 5.0 | mA |
| $\mathrm{V}_{\text {OL }}$ | Output Voltage, Low | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{F} \text { (on) }} \text { max. } \\ & \hline \end{aligned}$ | All |  | 0.2 | 0.4 | V |
| $\mathrm{I}_{\text {(on) }}$ | Turn-On Threshold Current ${ }^{(2)}$ | $\mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$ | H11L1M |  |  | 1.6 | mA |
|  |  |  | H11L2M |  |  | 10.0 |  |
|  |  |  | H11L3M |  |  | 5.0 |  |
| $\mathrm{I}_{\text {(off) }}$ | Turn-Off Threshold Current | $\mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$ | All | 0.3 | 1.0 |  | mA |
| $\mathrm{I}_{\text {(off) }} / I_{\text {F(on) }}$ | Hysteresis Ratio | $\mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$ | All | 0.50 | 0.75 | 0.90 |  |
| AC Characteristics, Switching Speed |  |  |  |  |  |  |  |
| $\mathrm{t}_{\text {on }}$ | Turn-On Time | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{F} \text { (on) })}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | All |  | 1.0 | 4.0 | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{f}}$ | Fall Time | $\begin{aligned} & \hline \mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{F} \text { (on) })}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | All |  | 0.1 |  | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\text {off }}$ | Turn-Off Time | $\begin{aligned} & \hline \mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{F}(\mathrm{on}),}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | All |  | 1.2 | 4.0 | $\mu \mathrm{s}$ |
| $\mathrm{t}_{\mathrm{r}}$ | Rise Time | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=270 \Omega, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{F} \text { (on) })}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} \end{aligned}$ | All |  | 0.1 |  | $\mu \mathrm{s}$ |
|  | Data Rate |  | All |  | 1.0 |  | MHz |

## Isolation Characteristics

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
| :---: | :--- | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {ISO }}$ | Input-Output Isolation Voltage | $\mathrm{t}=1$ Minute | 4170 |  |  | $\mathrm{VAC}_{\mathrm{RMS}}$ |
| $\mathrm{C}_{\text {ISO }}$ | Isolation Capacitance | $\mathrm{V}_{\mathrm{I}-\mathrm{O}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 0.4 | 0.6 | pF |
| $\mathrm{R}_{\text {ISO }}$ | Isolation Resistance | $\mathrm{V}_{\mathrm{I}-\mathrm{O}}= \pm 500 \mathrm{VDC}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | $10^{11}$ |  |  | $\Omega$ |

## Note:

2. Maximum $\mathrm{I}_{\mathrm{F}(\mathrm{ON})}$ is the maximum current required to trigger the output. For example, a 1.6 mA maximum trigger current would require the LED to be driven at a current greater than 1.6 mA to guarantee the device turns on. A $10 \%$ guard band is recommended to account for degradation of the LED over its lifetime. The maximum allowable LED drive current is 30 mA .

Typical Performance Curves


Figure 3. Transfer Characteristics


Figure 5. Threshold Current vs. Supply Temperature


Figure 7. Supply Current vs. Supply Voltage


Figure 4. Threshold Current vs. Supply Voltage


Figure 6. Output Voltage, Low vs. Load Current


Figure 8. LED Forward Voltage vs. Forward Current

Typical Performance Curves (Continued)


Figure 9. Switching Test Circuit and Waveforms

## Reflow Profile



Figure 10. Reflow Profile

## Ordering Information

| Part Number | Package | Packing Method |
| :--- | :--- | :--- |
| H11L1M | DIP 6-Pin | Tube (50 Units) |
| H11L1SM | SMT 6-Pin (Lead Bend) | Tube (50 Units) |
| H11L1SR2M | SMT 6-Pin (Lead Bend) | Tape and Reel (1000 Units) |
| H11L1VM | DIP 6-Pin, DIN EN/IEC60747-5-5 Option | Tube (50 Units) |
| H11L1SVM | SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option | Tube (50 Units) |
| H11L1SR2VM | SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option | Tape and Reel (1000 Units) |
| H11L1TVM | DIP 6-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 Option | Tube (50 Units) |

## Note:

3. The product orderable part number system listed in this table also applies to the H11L2M and H11L3M product families.

## Marking Information



Figure 11. Top Mark
Table 1. Top Mark Definitions

| 1 | Fairchild Logo |
| :--- | :--- |
| 2 | Device Number |
| 3 | DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option) |
| 4 | One-Digit Year Code, e.g., "4" |
| 5 | Digit Work Week, Ranging from "01" to "53" |
| 6 | Assembly Package Code |



NOTES:
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$3.28-3.53$

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